

NI DAQPad™ -6020E Family Specifications

This document lists the I/O terminal summary and specifications for the NI DAQPad-6020E family of devices. This family includes the following devices:

- NI DAQPad-6020E (Half-Size Box)
- NI DAQPad-6020E (Full-Size Box)
- NI DAQPad-6020E BNC

I/O Terminal Summary



Note With NI-DAQmx, National Instruments revised its terminal names so they are easier to understand and more consistent among NI hardware and software products. The revised terminal names used in this document are usually similar to the names they replace. For a complete list of Traditional NI-DAQ (Legacy) terminal names and their NI-DAQmx equivalents, refer to *Terminal Name Equivalents* of the *E Series Help*.

Table 1. I/O Terminals

Terminal Name	Terminal Type and Direction	Impedance Input/ Output	Protection (V) On/Off	Source (mA at V)	Sink (mA at V)	Rise Time (ns)	Bias
AI <0..15>	AI	100 GΩ in parallel with 50 pF	35/25	—	—	—	±200 pA
AI SENSE	AI	100 GΩ in parallel with 50 pF	35/25	—	—	—	±200 pA
AI GND	—	—	—	—	—	—	—
AO 0	AO	0.1 Ω	Short-circuit to ground	5 at 10	5 at -10	15 V/μs	—
AO 1	AO	0.1 Ω	Short-circuit to ground	5 at 10	5 at -10	15 V/μs	—
AO EXT REF	AI	10 kΩ	35/25	—	—	—	—
AO GND	—	—	—	—	—	—	—
D GND	—	—	—	—	—	—	—

Table 1. I/O Terminals (Continued)

Terminal Name	Terminal Type and Direction	Impedance Input/ Output	Protection (V) On/Off	Source (mA at V)	Sink (mA at V)	Rise Time (ns)	Bias
+5 V	—	0.1 Ω	Short-circuit to ground	1 A	—	—	—
P0.<0..7>	DIO	—	$V_{CC} + 0.5$	13 at ($V_{CC} - 0.4$)	24 at 0.4	1.1	50 k Ω pu [†]
AI HOLD COMP	DO	—	—	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
EXT STROBE*	DO	—	—	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 0/ (AI START TRIG)	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 1/ (AI REF TRIG)	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 2/ (AI CONV CLK)*	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 3/ CTR 1 SOURCE	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 4/CTR 1 GATE	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
CTR 1 OUT	DO	—	—	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 5/ (AO SAMP CLK)*	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 6/ (AO START TRIG)	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 7/ (AI SAMP CLK)	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 8/ CTR 0 SOURCE	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
PFI 9/CTR 0 GATE	DIO	—	$V_{CC} + 0.5$	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu
CTR 0 OUT	DO	—	—	3.5 at ($V_{CC} - 0.4$)	5 at 0.4	1.5	50 k Ω pu

Table 1. I/O Terminals (Continued)

Terminal Name	Terminal Type and Direction	Impedance Input/ Output	Protection (V) On/Off	Source (mA at V)	Sink (mA at V)	Rise Time (ns)	Bias
FREQ OUT	DO	—	—	3.5 at (V _{CC} - 0.4)	5 at 0.4	1.5	50 kΩ pu

* Indicates active low.
† P0.<6..7> are also pulled down with a 50 kΩ resistor.
AI = Analog Input DIO = Digital Input/Output pu = pull-up
AO = Analog Output DO = Digital Output
Note: The tolerance on the 50 kΩ pull-up resistors is large. Actual value might range between 17 kΩ and 100 kΩ.

Specifications

The following specifications are typical at 25 °C unless otherwise noted.

Analog Input

Input Characteristics

Number of channels 16 single-ended
or 8 differential
(software-selectable)

Type of A/D converter (ADC)..... Successive
approximation

Resolution 12 bits, 1 in 4,096

Max sampling rate 100 kS/s guaranteed

Input signal ranges

Range (Software-Selectable)	Input Range	
	Bipolar	Unipolar
20 V	±10 V	—
10 V	±5 V	0 to 10 V
5 V	±2.5 V	0 to 5 V
2 V	±1 V	0 to 2 V
1 V	±500 mV	0 to 1 V
500 mV	±250 mV	0 to 500 mV
200 mV	±100 mV	0 to 200 mV
100 mV	±50 mV	0 to 100 mV

Input couplingDC

Max working voltage
(signal + common mode).....Each input should remain
within ±11 V of ground

Overvoltage protection

Powered on±35 V

Powered off.....±25 V

Inputs protectedAI <0..15>, AI SENSE

FIFO buffer size4,096 samples (S)

Data transfers.....Interrupts,
programmed I/O

Configuration memory size512 words
(1 word = 8 bits)

Accuracy Information

Nominal Range at Full Scale (V)	Absolute Accuracy							Relative Accuracy Resolution (mV)	
	% of Reading		Offset (mV)	Noise + Quantization (μV)		Temp Drift ($\%/^{\circ}\text{C}$)	Absolute Accuracy at Full Scale (mV)	Single Pt.	Averaged
	24 Hours	1 Year		Single Pt.	Averaged				
± 10.0	0.072	0.076	6.380	3.467	0.846	0.0010	14.826	5.729	1.114
± 5.0	0.019	0.021	3.198	1.733	0.423	0.0005	4.6710	2.865	0.557
± 2.5	0.072	0.076	1.608	0.867	0.211	0.0010	3.7190	1.432	0.278
± 1.0	0.072	0.076	0.653	0.347	0.085	0.0010	1.4980	0.573	0.111
± 0.5	0.072	0.076	0.335	0.173	0.042	0.0010	0.7570	0.286	0.056
± 0.25	0.072	0.076	0.176	0.105	0.021	0.0010	0.3870	0.151	0.028
± 0.1	0.072	0.076	0.081	0.061	0.008	0.0010	0.1650	0.074	0.011
± 0.05	0.072	0.076	0.049	0.049	0.004	0.0010	0.0910	0.056	0.006
0 to 10	0.019	0.021	3.198	1.733	0.423	0.0005	5.7210	2.865	0.557
0 to 5	0.072	0.076	1.608	0.867	0.211	0.0010	5.6190	1.432	0.278
0 to 2	0.072	0.076	0.653	0.347	0.085	0.0010	2.2580	0.573	0.111
0 to 1	0.072	0.076	0.335	0.173	0.042	0.0010	1.1370	0.286	0.056
0 to 0.5	0.072	0.076	0.176	0.105	0.021	0.0010	0.5770	0.151	0.028
0 to 0.2	0.072	0.076	0.081	0.061	0.008	0.0010	0.2410	0.074	0.011
0 to 0.1	0.072	0.076	0.049	0.049	0.004	0.0010	0.1290	0.056	0.006

Note: Accuracies are valid for measurements following an internal E Series calibration. Averaged numbers assume dithering and averaging of 100 single-channel readings. Measurement accuracies are listed for operational temperatures within $\pm 1^{\circ}\text{C}$ of internal calibration temperature and $\pm 10^{\circ}\text{C}$ of external or factory-calibration temperature. NI recommends a one-year calibration interval. The Absolute Accuracy at Full Scale calculations were performed for a maximum range input voltage (for example, 10 V for the ± 10 V range) after one year, assuming 100 points of averaged data. Go to ni.com/info and enter info code `rdspec` for example calculations.

Transfer Characteristics

Relative accuracy

Dithered ± 0.2 LSB typ
 Undithered ± 1.5 LSB max undithered

Differential nonlinearity (DNL) ± 0.2 LSB typ,
 ± 1.0 LSB max

No missing codes 12 bits, guaranteed

Offset error

Pregain error after calibration ± 2 μV max
 Pregain error before
 calibration ± 24 mV max

Postgain error after calibration ... ± 0.5 mV max

Postgain error before
 calibration ± 100 mV max

Gain error (relative to calibration reference)

After calibration (gain = 1) $\pm 0.02\%$ of reading max
 Before calibration $\pm 2.0\%$ of reading max
 Gain $\neq 1$ with gain error
 adjusted to 0 at gain = 1 $\pm 0.05\%$ of reading max

Amplifier Characteristics

Input impedance 68-pin
 I/O connector 100 GΩ in parallel
 with 50 pF

BNC version

Powered on

CH+ (AI <0..7>) 100 GΩ in parallel
 with 50 pF

CH- (AI <8..15>)

With built-in bias resistor
 disengaged 100 GΩ in parallel
 with 50 pF

With built-in bias resistor
 engaged (default) 100 Ω in parallel
 with 50 pF

Powered off 3 kΩ min

Overload 3 kΩ min

Input bias current ±200 pA

Input offset current ±100 pA

Common-mode rejection ratio (CMRR),
 100 mV to 20 V 90 dB, DC to 60 Hz

Dynamic Characteristics

Bandwidth

Small signal (-3 dB) 150 kHz

Large signal (1% THD) 200 kHz

Settling time for full-scale step 10 μs max to ±0.5 LSB
 accuracy¹

System noise (LSB_{rms}, not including quantization)

Range	Dither Off	Dither On
1 to 20 V	0.07	0.5
500 mV	0.12	0.5
200 mV	0.25	0.6
100 mV	0.5	0.7

Crosstalk, DC to 100 kHz

Adjacent channels -60 dB

All other channels -80 dB

Stability

Recommended warm-up time 30 minutes

Offset temperature coefficient

Pregain ±15 μV/°C

Postgain ±240 μV/°C

Gain temperature coefficient ±20 ppm/°C

Onboard calibration reference

Level 5.000 V (±2.5 mV), actual
 value stored in EEPROM

Temperature coefficient ±5 ppm/°C max

Long-term stability ±15 ppm/√1,000 h

Analog Output

Output Characteristics

Number of channels 2 voltage

Resolution 12 bits, 1 in 4,096

Max update rate 20 S/s
 (system-dependent)

Type of D/A converter (DAC) Double-buffered,
 multiplying

FIFO buffer size None

Data transfers Interrupts,
 programmed I/O

¹ Accuracy values are valid for source impedances <1 kΩ. Refer to *Multichannel Scanning Considerations of the E Series Help* for more information.

Accuracy Information

Nominal Range (V)		Absolute Accuracy					Absolute Accuracy at Full Scale (mV)
Positive Full Scale	Negative Full Scale	% of Reading			Offset (μV)	Temp Drift (%/°C)	
		24 Hours	90 Days	1 Year			
10	-10	0.018	0.020	0.022	5.93	0.0005	8.133
10	0	0.018	0.020	0.022	3.49	0.0005	5.691

Note: Accuracies are valid for measurements following an internal E Series calibration. Averaged numbers assume dithering and averaging of 100 single-channel readings. Measurement accuracies are listed for operational temperatures within ± 1 °C of internal calibration temperature and ± 10 °C of external or factory-calibration temperature. NI recommends a one-year calibration interval. The Absolute Accuracy at Full Scale calculations were performed for a maximum range input voltage (for example, 10 V for the ± 10 V range) after one year, assuming 100 points of averaged data. Go to ni.com/info and enter info code `rdspec` for example calculations.

Transfer Characteristics

Relative accuracy, or integral non-linearity (INL)

After calibration ± 0.3 LSB typ,
 ± 0.5 LSB max
 Before calibration ± 4 LSB max

DNL

After calibration ± 0.3 LSB typ,
 ± 1.0 LSB max
 Before calibration ± 3 LSB max

Monotonicity 12 bits, guaranteed
 after calibration

Offset error

After calibration ± 1.0 mV max
 Before calibration ± 200 mV max

Gain error (relative to internal reference)

After calibration $\pm 0.01\%$ of output max
 Before calibration $\pm 0.5\%$ of output max

Gain error

(relative to external reference) 0% to $+0.5\%$ of output
 max, not adjustable

Voltage Output

Ranges ± 10 V, 0 to 10 V,
 \pm AO EXT REF,
 0 to AO EXT REF
 (software-selectable)

Output coupling DC

Output impedance 0.1Ω max

Current drive ± 5 mA max

Protection Short-circuit to ground

Power-on state 0 V (± 200 mV)

External reference input

Range ± 11 V

Overvoltage protection

Powered on ± 35 V

Powered off ± 25 V

Input impedance 10 k Ω

Bandwidth (-3 dB) 300 kHz

Dynamic Characteristics

Settling time for full-scale step 10 μ s to ± 0.5 LSB
 accuracy

Slew rate 10 V/ μ s

Noise 200 μ V_{rms}, DC to 1 MHz

Glitch energy (at midscale transition)

Magnitude ± 100 mV

Duration 3 μ s

Stability

Offset temperature coefficient ± 50 μ V/°C

Gain temperature coefficient

Internal reference ± 25 ppm/°C

External reference ± 25 ppm/°C

Onboard calibration reference

Level 5.000 V (± 2.5 mV), actual
 value stored in EEPROM

Temperature coefficient ± 5 ppm/°C max

Long-term stability ± 15 ppm/ $\sqrt{1,000}$ h

Digital I/O

Number of channels 8 input/output

Compatibility 5 V TTL

Digital logic levels on P0.<0..7>

Level	Min	Max
Input low voltage	0 V	0.8 V
Input high voltage	2.0 V	5.0 V
Input low current ($V_{in} = 0$ V)	—	-320 μ A
Input high current ($V_{in} = 5$ V)	—	10 μ A
Output low voltage ($I_{OL} = 24$ mA)	—	0.4 V
Output high voltage ($I_{OH} = -13$ mA)	4.35 V	—

Data transfers Programmed I/O

Timing I/O

Number of channels 2 up/down
counter/timers,
1 frequency scaler

Resolution

Counter/timers 24 bits (1 in 16,777,216)

Frequency scalars 4 bits

Compatibility 5 V TTL/CMOS

Base clocks available

Counter/timers 20 MHz, 100 kHz

Frequency scaler 10 MHz, 100 kHz

Base clock accuracy $\pm 0.01\%$

Max source frequency

up/down counter/timers 20 MHz

Min source pulse duration 10 ns in edge-detect mode

Min gate pulse duration 10 ns in edge-detect mode

Data transfers Interrupts,
programmed I/O

Digital Trigger

Purpose

Analog input Start, reference,
and pause trigger,
sample clock

Analog output Start and pause trigger,
sample clock

Counter/timers Source, gate

Source PFI <0..9>

Compatibility 5 V TTL

Response Rising or falling edge

Pulse width 10 ns min

Calibration

Recommended warm-up time 30 minutes

Calibration interval 1 year

Onboard calibration reference level

DC level 5.000 V (± 3.5 mV)
over full operating
temperature, actual value
stored in EEPROM

Temperature coefficient ± 5.0 ppm/ $^{\circ}$ C max

Long-term stability ± 15.0 ppm/ $\sqrt{1,000}$ h

Bus Interface

Type USB full-speed

Power Requirement

9 to 30 VDC 15 W

Power available at I/O connector ... +4.65 to +5.25 VDC
at 1 A



Note Power supply voltage should never go below 8.5 V, including AC ripple.

Physical

Dimensions

DAQPad-6020E (full-size box)

DAQPad-6020E BNC 25.4 cm \times 30.7 cm \times
4.3 cm
(10 in. \times 12.1 in. \times 1.7 in.)

DAQPad (half-size box) 14.6 cm \times 21.3 cm \times
3.8 cm
(5.8 in. \times 8.4 in. \times 1.5 in.)

Weight

NI DAQPad-6020E
(half-size box) 806 g (1 lb 12.4 oz)

NI DAQPad-6020E
(full-size box) 1703 g (3 lb 12 oz)

NI DAQPad-6020E BNC 1886 g (4 lb 2.5 oz)

I/O connector 68-pin male SCSI-II type

Maximum Working Voltage

Maximum working voltage refers to the signal voltage plus the common-mode voltage.

Channel-to-earth	11 V, Installation Category I
Channel-to-channel	11 V, Installation Category I

Environmental

Operating temperature	0 to 55 °C
Storage temperature	-55 to 150 °C
Relative humidity	10 to 90%, noncondensing
Maximum altitude	2,000 m
Pollution Degree (indoor use only)	2

Safety

This product is designed to meet the requirements of the following standards of safety for electrical equipment for measurement, control, and laboratory use:

- IEC 60950-1, EN 60950-1
- UL 60950-1
- CAN/CSA-C22.2 No. 60950-1



Note For UL and other safety certifications, refer to the product label, or visit ni.com/certification, search by model number or product line, and click the appropriate link in the Certification column.

Electromagnetic Compatibility

Emissions	EN 55011 Class A at 10 m FCC Part 15A above 1 GHz
Immunity	EN 61326:1997 A2:2001, Table 1

CE, C-Tick, and FCC Part 15 (Class A) Compliant



Note For EMC compliance, you must operate this device with shielded cabling.

CE Compliance

This product meets the essential requirements of applicable European Directives, as amended for CE marking, as follows:

Low-Voltage Directive (safety) 73/23/EEC

Electromagnetic Compatibility
Directive (EMC) 89/336/EEC



Note Refer to the Declaration of Conformity (DoC) for this product for any additional regulatory compliance information. To obtain the DoC for this product, visit ni.com/certification, search by model number or product line, and click the appropriate link in the Certification column.

AI 8	34	68	AI 0
AI 1	33	67	AI GND
AI GND	32	66	AI 9
AI 10	31	65	AI 2
AI 3	30	64	AI GND
AI GND	29	63	AI 11
AI 4	28	62	AI SENSE
AI GND	27	61	AI 12
AI 13	26	60	AI 5
AI 6	25	59	AI GND
AI GND	24	58	AI 14
AI 15	23	57	AI 7
AO 0	22	56	AI GND
AO 1	21	55	AO GND
AO EXT REF	20	54	AO GND
P0.4	19	53	D GND
D GND	18	52	P0.0
P0.1	17	51	P0.5
P0.6	16	50	D GND
D GND	15	49	P0.2
+5 V	14	48	P0.7
D GND	13	47	P0.3
D GND	12	46	AI HOLD COMP
PFI 0/AI START TRIG	11	45	EXT STROBE
PFI 1/AI REF TRIG	10	44	D GND
D GND	9	43	PFI 2/AI CONV CLK
+5 V	8	42	PFI 3/CTR 1 SRC
D GND	7	41	PFI 4/CTR 1 GATE
PFI 5/AO SAMP CLK	6	40	CTR 1 OUT
PFI 6/AO START TRIG	5	39	D GND
D GND	4	38	PFI 7/AI SAMP CLK
PFI 9/CTR 0 GATE	3	37	PFI 8/CTR 0 SRC
CTR 0 OUT	2	36	D GND
FREQ OUT	1	35	D GND

Figure 1. NI DAQPad-6020E (Full- and Half-Size Box) Pinout

PFI 9	2	1	P0.7
PFI 8	4	3	P0.6
PFI 7	6	5	P0.5
PFI 6	8	7	P0.4
PFI 5	10	9	P0.3
PFI 4	12	11	P0.2
PFI 3	14	13	P0.1
PFI 2	16	15	P0.0
PFI 1	18	17	CTR 1 OUT
D GND	20	19	D GND
USER 2	22	21	USER 1
FREQ OUT	24	23	AI HOLD COMP
+5 V	26	25	EXT STROBE
+5 V	28	27	AI SENSE
D GND	30	29	AI GND

Figure 2. NI DAQPad-6020E BNC Pinout

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